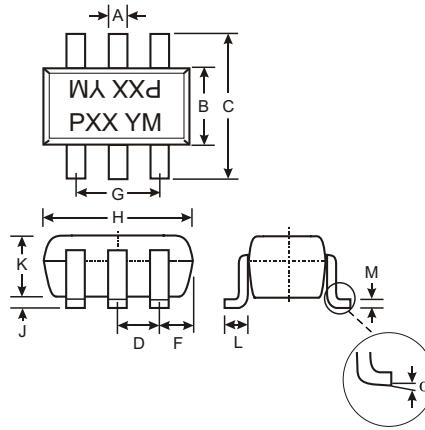


Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDC)
- Built-In Biasing Resistors
- Lead-Free Device

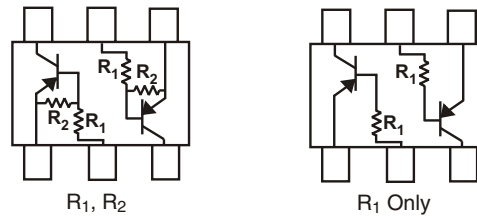
Mechanical Data

- Case: SOT-363, Molded Plastic
- Case material - UL Flammability Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Finish - Matte Tin Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 2)
- Weight: 0.006 grams (approx.)
- Ordering Information (See Page 2)



SOT-363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
F	0.30	0.40
H	1.80	2.20
J	—	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.25
α	0°	8°
All Dimensions in mm		

P/N	R1 (NOM)	R2 (NOM)	MARKING
DDA122LU	0.22K	10K	P81
DDA142JU	0.47K	10K	P82
DDA122TU	0.22K	OPEN	P83
DDA142TU	0.47K	OPEN	P84



SCHMATIC DIAGRAM

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage	V _{CC}	-50	V
Input Voltage	V _{IN}	+5 to -6 +5 to -6	V
Input Voltage	V _{EBO (MAX)}	-5	V
Output Current	I _C	-100	mA
Power Dissipation (Note 3)	P _d	200	mW
Thermal Resistance, Junction to Ambient Air (Note 3)	R _{θJA}	625	°C/W
Operating and Storage and Temperature Range	T _j , T _{STG}	-55 to +150	°C

- Note:
1. If lead-bearing terminal plating is required, please contact your Diodes Inc. sales representative for availability and minimum order details.
 2. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.
 3. 150mW per element must not be exceeded.

Electrical Characteristics @ T_A = 25°C unless otherwise specified **R1, R2 Types**

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DDA122LU DDA142JU	V _{I(off)}	-0.3 -0.3	—	—	V	V _{CC} = -5V, I _O = -100μA
	DDA122LU DDA142JU	V _{I(on)}	—	—	-2.0 -2.0	V	V _O = -0.3V, I _O = -20mA V _O = -0.3V, I _O = -20mA
Output Voltage		V _{O(on)}	—	—	-0.3V	V	I _O /I _I = -5mA/-0.25mA
Input Current	DDA122LU DDA142JU	I _I	—	—	-28 -13	mA	V _I = -5V
Output Current		I _{O(off)}	—	—	-0.5	μA	V _{CC} = -50V, V _I = 0V
DC Current Gain	DDA122LU DDA142JU	G _I	56 56	—	—	—	V _O = -5V, I _O = -10mA
Gain-Bandwidth Product*		f _T	—	200	—	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

* Transistor - For Reference Only

Electrical Characteristics @ T_A = 25°C unless otherwise specified **R1 Only Types**

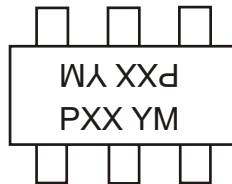
Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV _{CBO}	-50	—	—	V	I _C = -50μA
Collector-Emitter Breakdown Voltage		BV _{CEO}	-40	—	—	V	I _C = -1mA
Emitter-Base Breakdown Voltage	DDA122TU DDA142TU	BV _{EBO}	-5	—	—	V	I _E = -50μA I _E = -50μA
Collector Cutoff Current		I _{CBO}	—	—	-0.5	μA	V _{CB} = -50V
Emitter Cutoff Current	DDA122TU DDA142TU	I _{EBO}	—	—	-0.5 -0.5	μA	V _{EB} = -4V
Collector-Emitter Saturation Voltage		V _{CE(sat)}	—	—	-0.3	V	I _C = -5mA, I _B = -0.25mA
DC Current Transfer Ratio	DDA122TU DDA142TU	h _{FE}	100 100	250 250	600 600	—	I _C = -1mA, V _{CE} = -5V
Gain-Bandwidth Product*		f _T	—	200	—	MHz	V _{CE} = -10V, I _E = 5mA, f = 100MHz

* Transistor - For Reference Only

Ordering Information (Note 4)

Device	Packaging	Shipping
DDA122LU-7	SOT-363	3000/Tape & Reel
DDA142JU-7	SOT-363	3000/Tape & Reel
DDA122TU-7	SOT-363	3000/Tape & Reel
DDA142TU-7	SOT-363	3000/Tape & Reel

- Notes: 1. If lead-bearing terminal plating is required, please contact your Diodes Inc. sales representative for availability and minimum order details.
4. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information


PXX = Product Type Marking Code
See Sheet 1 Diagrams
YM = Date Code Marking
Y = Year ex: N = 2002
M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009
Code	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

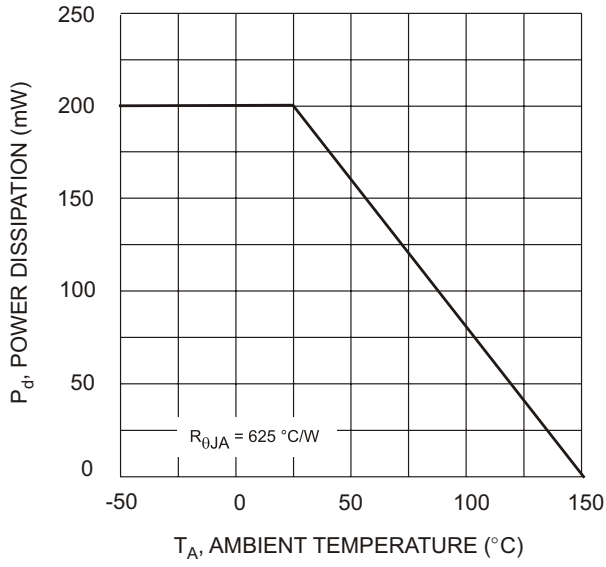


Fig. 1 Power Derating Curve

(150mW per element must not be exceeded).